Diode Semiconductor Device - Page 1 of 1



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**Function For Which Designed:** Transient suppressor **Mounting Method:** Terminal **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 33.9 breakdown voltage, dc and 38.2 breakdown voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes drain current nanoamperes **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pn **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0